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<u>Diodes Incorporated</u> <u>ZX5T1951GTA</u>

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Datasheet of ZX5T1951GTA - TRANS PNP 60V 6A SOT223

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A Product Line of Diodes Incorporated



ZX5T1951G

#### **60V PNP MEDIUM POWER TRANSISTOR IN SOT223**

#### **Features**

- BV<sub>CEO</sub> > -60V
- I<sub>C</sub> = -6A Continuous Collector Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < -95mV max @ -1A</li>
- $R_{CE(sat)} = 40m\Omega$  for a low Equivalent On-Resistance
- hFE Specified up to -10A for a High Gain Hold-Up
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

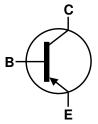
- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 <a>®3</a>
- Weight: 0.112 grams (Approximate)

#### **Applications**

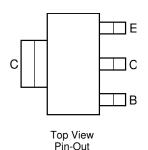
- Motor Driving
- DC-DC Modules
- Backlight Inverters
- Actuator, Relay, and Solenoid Drivers



Top View



Device Symbol



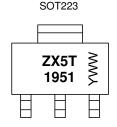
### Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZX5T1951GTA	ZX5T1951	7	12	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-Free, "Green" and Lead-Free.
- 3. Halogen- and Antimony-Free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

#### Marking Information



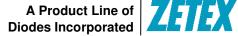
ZX5T1951 = Product Type Marking Code YWW = Date Code Marking Y or  $\overline{Y}$  = Last Digit of Year (ex: 5= 2015) WW or  $\overline{W}W$  = Week Code (01~53)



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### Absolute Maximum Ratings (@TA = +25 ℃, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-90	V
Collector-Emitter Voltage	V <sub>CES</sub>	-90	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-60	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current (Note 5)	Ic	-6	Α
Peak Pulse Current	I <sub>CM</sub>	-15	Α
Base Current	I <sub>B</sub>	-1	Α

## Thermal Characteristics (@T<sub>A</sub> = +25 °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)		3.0 24	W	
Linear Derating Factor	(Note 6)	P <sub>D</sub>	1.6 12.8	mW /°C	
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	42		
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{ heta JA}$	78	°C/W	
Thermal Resistance Junction to Lead (Note 7)		$R_{ heta JL}$	12.3	]	
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	∞		

### ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
- 7. Thermal resistance from junction to solder-point (at the end of the collector lead).

  8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

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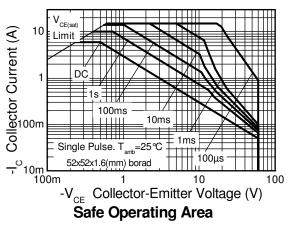
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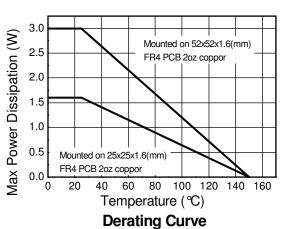


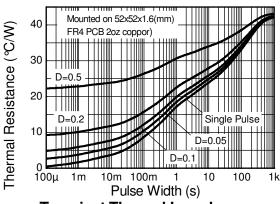


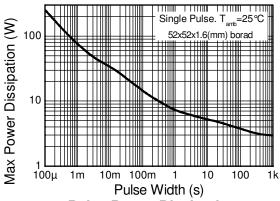
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### **Thermal Characteristics**









**Transient Thermal Impedance** 

**Pulse Power Dissipation** 



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## **Electrical Characteristics** (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-90	-120	-	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage	BV <sub>CES</sub>	-90	-120	-	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	-60	-80	-	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	$BV_{EBO}$	-7	-8	-	V	$I_E = -100 \mu A$
Collector-Base Cut-Off Current	I <sub>CBO</sub>	-	<1	-50	nA	$V_{CB} = -72V$
Collector-Emitter Cut-Off Current	I <sub>CES</sub>	-	<1	-50	nA	V <sub>CB</sub> = -72V
Emitter Cutoff Current	I <sub>EBO</sub>	-	<1	-10	nA	V <sub>EB</sub> = -6V
		100	240			$I_C = -10 \text{mA}, V_{CE} = -2 \text{V}$
Static Forward Current Transfer Patic (Note 0)	h	100	180	300		$I_C = -2A$ , $V_{CE} = -2V$
Static Forward Current Transfer Ratio (Note 9)	h <sub>FE</sub>	40	70		-	$I_C = -5A$ , $V_{CE} = -2V$
		5	14	-		I <sub>C</sub> = -10A, V <sub>CE</sub> = -2V
		-	-16	-30	mV	I <sub>C</sub> = -100mA, I <sub>B</sub> = -10mA
Collector Emitter Seturation Voltage (Note 0)	V <sub>CE(sat)</sub>	-	-55	-95		$I_C = -1A$ , $I_B = -100mA$
Collector-Emitter Saturation Voltage (Note 9)		-	-85	-130		I <sub>C</sub> = -2A, I <sub>B</sub> = -200mA
		-	-200	-260		I <sub>C</sub> = -5A, I <sub>B</sub> = -500mA
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	-	-1	-1.15	V	I <sub>C</sub> = -5A, I <sub>B</sub> = -500mV
Base-Emitter Turn-On Voltage (Note 9)	V <sub>BE(on)</sub>	-	-0.89	-1.0	V	I <sub>C</sub> = -5A, V <sub>CE</sub> = -2V
Output Capacitance (Note 9)	$C_obo$	-	33	70	pF	V <sub>CB</sub> = -10V. f = 1MHz
Transition Frequency	f⊤	-	120	-	MHz	$V_{CE} = -10V, I_{C} = -100mA$ f = 50MHz
0 11 11 71	t <sub>on</sub>	-	33	80		V <sub>CC</sub> = -10V, I <sub>C</sub> = -2A
Switching Time	t <sub>off</sub>	-	215	300	ns	$I_{B1} = -I_{B2} = -200 \text{mA}$

9. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%. Note:

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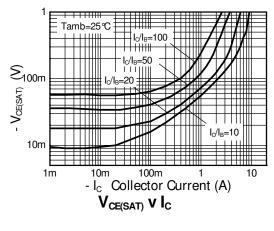
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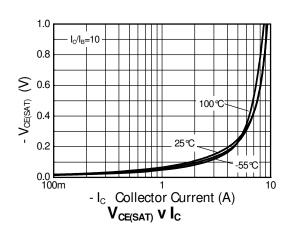


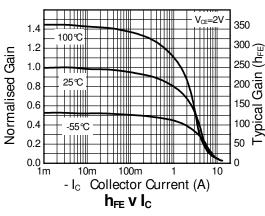


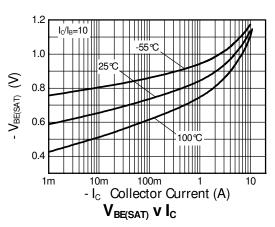
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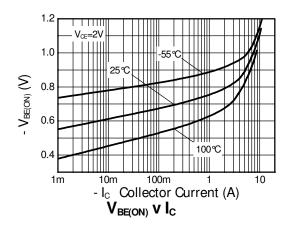
### Typical Electrical Characteristics (@TA = +25 °C, unless otherwise specified.)







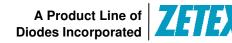




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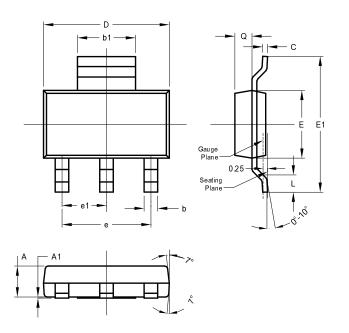




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#### **Package Outline Dimensions**

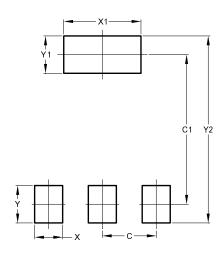
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Q	0.84	0.94	0.89		
All Dimensions in mm					

### **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)		
С	2.30		
C1	6.40		
X	1.20		
X1	3.30		
Υ	1.60		
Y1	1.60		
Y2	8.00		



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